

TOSHIBA Photocoupler GaAs IRED & Photo-MOSFET

TLP176D

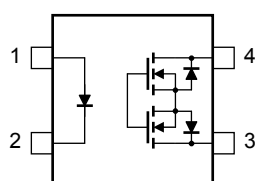
Modem in PC
Modem · Fax Card
Telecommunication

The TOSHIBA TLP176D consists of gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a SOP, which is suitable for surface mount assembly.

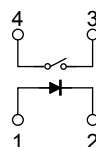
The TLP176D is suitable for modem and PBX applications which require space savings.

- SOP 4 pin (2.54SOP4): 1-form-A
- Peak off-state voltage: 200 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 200 mA (max)
- On-state resistance: 8 Ω (max)
- Isolation voltage: 1500 Vrms (min)
- UL recognized: UL1577, file No. E67349

Pin Configuration (top view)

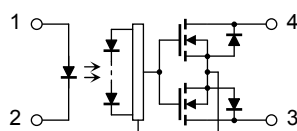


1-form A

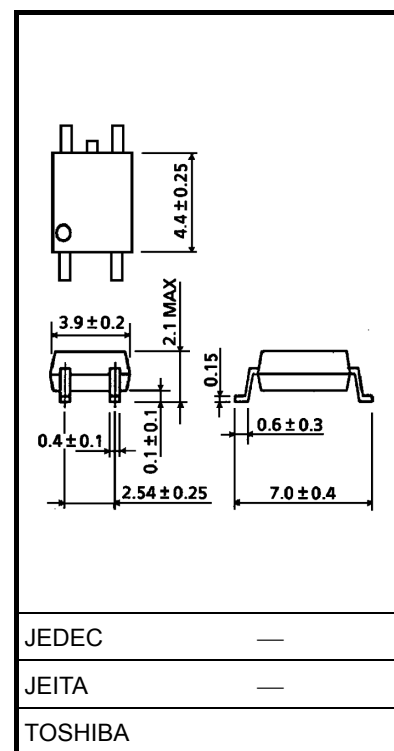


1: Anode
2: Cathode
3: Drain
4: Drain

Internal Circuit



Unit: mm



Weight: 0.1 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
LED	Forward current	I_F	50	mA
	Forward current derating (Ta ≥ 25°C)	$\Delta I_F/^\circ\text{C}$	-0.5	mA/°C
	Pulse forward current (100 μs pulse, 100 pps)	I_{FP}	1	A
	Reverse voltage	V_R	5	V
	Junction temperature	T_j	125	°C
Detector	Off-state output terminal voltage	V_{OFF}	200	V
	On-state current	I_{ON}	200	mA
	On-state RMS current derating (Ta ≥ 25°C)	$\Delta I_{ON}/^\circ\text{C}$	-2.0	mA/°C
	Junction temperature	T_j	125	°C
Storage temperature range		T_{stg}	-55 to 125	°C
Operating temperature range		T_{opr}	-40 to 85	°C
Lead soldering temperature (10 s)		T_{sol}	260	°C
Isolation voltage (AC, 1 min., R.H. ≤ 60%) (Note)		BV_S	1500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note: Device considered a two-terminal device: pins1 and 2 shorted together and pins 3 and 4 shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Typ.	Max	Unit
Supply voltage	V_{DD}	—	150	200	V
Forward current	I_F	5	7.5	25	mA
On-state current	I_{ON}	—	—	130	mA
Operating temperature	T_{opr}	-20	—	65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Individual Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
Detector	Off-state current	I_{OFF}	$V_{OFF} = 200 \text{ V}$	—	—	1	μA
	Capacitance	C_{OFF}	$V = 0, f = 1 \text{ MHz}$	—	100	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Trigger LED current	I_{FT}	$I_{ON} = 200 \text{ mA}$	—	1	3	mA
On-state resistance	R_{ON}	$I_{ON} = 200 \text{ mA}, I_F = 5 \text{ mA}$	—	5	8	Ω

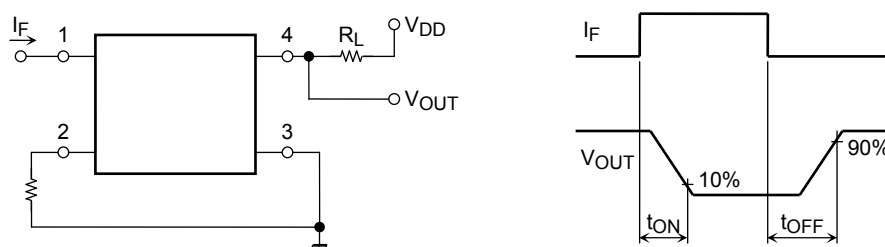
Isolation Characteristics (Ta = 25°C)

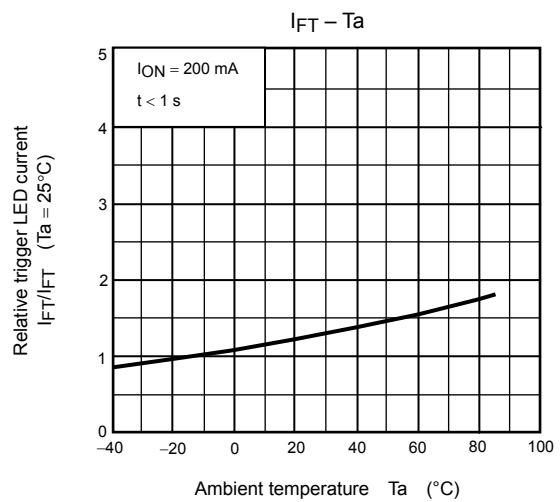
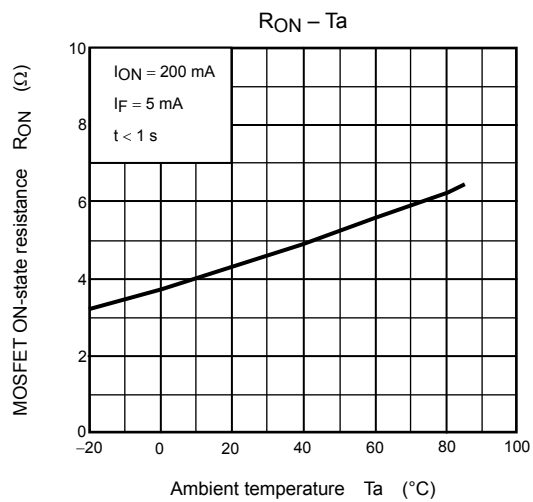
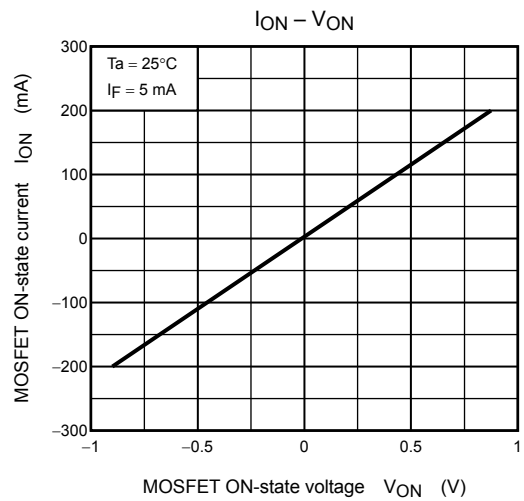
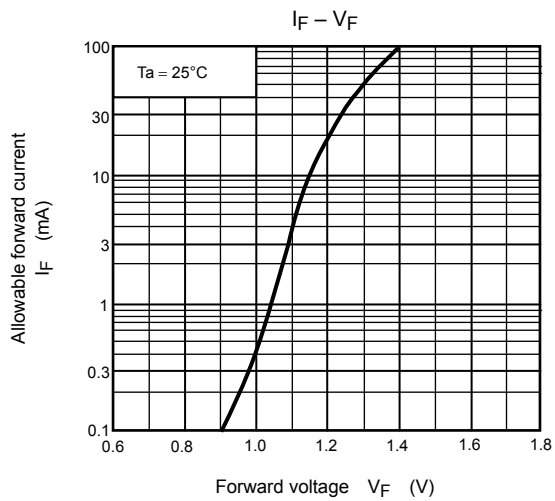
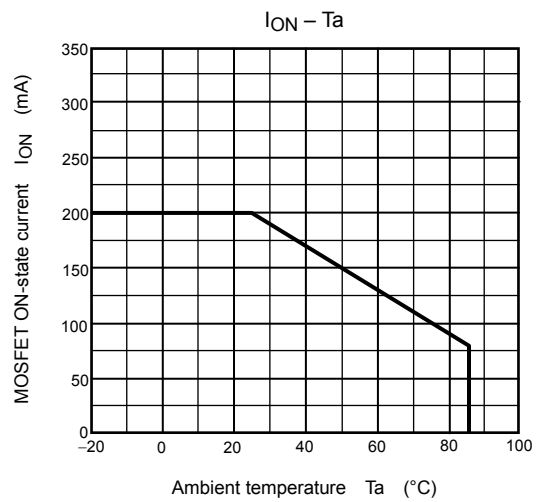
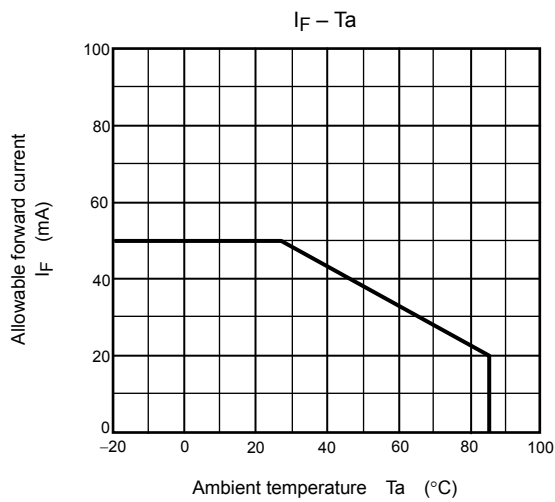
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance input to output	C_S	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation resistance	R_S	$V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$	5×10^{10}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1 minute	1500	—	—	Vrms
		AC, 1 second, in oil	—	3000	—	
		DC, 1 minute, in oil	—	3000	—	Vdc

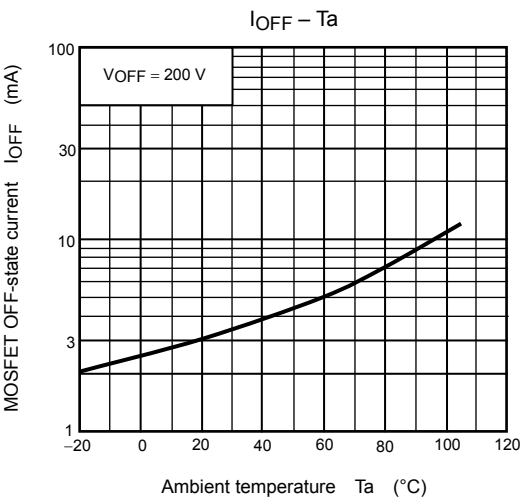
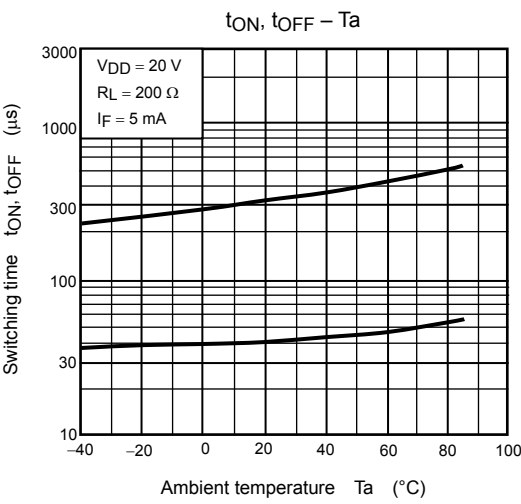
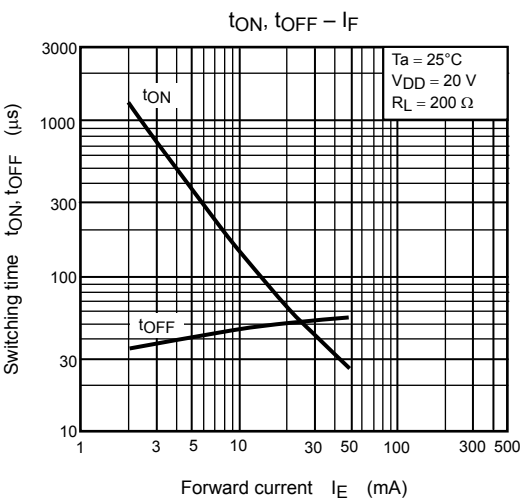
Switching Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Turn-on time	t_{ON}	$R_L = 200 \Omega$ $V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$ (Note)	—	0.6	1.5	ms
Turn-off time	t_{OFF}	$R_L = 200 \Omega$ $V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$ (Note)	—	0.1	1.0	ms

Note: Switching time test circuit







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